NSN 5961-01-185-9480

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View Online at https://aerobasegroup.com/nsn/5961-01-185-9480

Inclosure Material:

Metal

Overall Length:

0.900 inches

Overall Height:

0.225 inches

Overall Width:

0.405 inches

End Application:

Radar system an/fps-117

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Base

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

65.0 collector to base voltage/static/emitter open and 65.0 collector to emitter voltage, dc with base short-circuited to emitter and 3.5 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

5.00 milliamperes zero-gate-voltage source current preset and 12.50 milliamperes zero-gate-voltage source current minor

Power Rating Per Characteristic:

750.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

120.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Flange, base and leads plated; cap plating option gold

Precious Material:

Gold

Test Data Document:

80249-911319 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

1 case and 2 ribbon

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

